



#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

#### **Features**

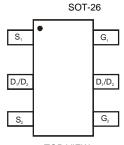
- Low Gate Charge
- Low R<sub>DS(ON)</sub>:
  - 28mΩ @V<sub>GS</sub> = 4.5V
  - 32mΩ @V<sub>GS</sub> = 2.5V
  - 40mΩ @V<sub>GS</sub> = 1.8V
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4)

#### **Mechanical Data**

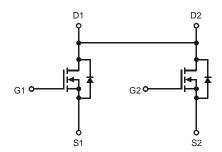
- Case: SOT-26
- Case Material Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)







TOP VIEW Pin Configuration



**Equivalent Circuit** 

### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		$V_{DSS}$	20	V
Gate-Source Voltage		V <sub>GSS</sub>	±8	V
Drain Current (Note 1) Continuous	$T_A = 25$ °C $T_A = 70$ °C	I <sub>D</sub>	4.2 3.2	Α
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	30	Α

#### Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P <sub>D</sub>	0.98	W
Thermal Resistance, Junction to Ambient (Note 1) t ≤10s	$R_{ heta JA}$	128	°C /W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Device mounted on 1"x1", FR-4 PC board with 2 oz. Copper and test pulse width t ≤10s.
- 2. Repetitive Rating, pulse width limited by junction temperature.
- 3. No purposefully added lead.
- 4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

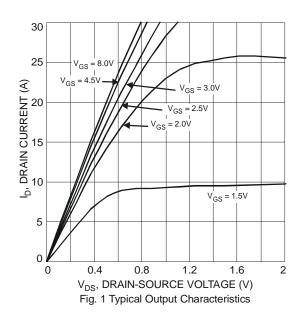


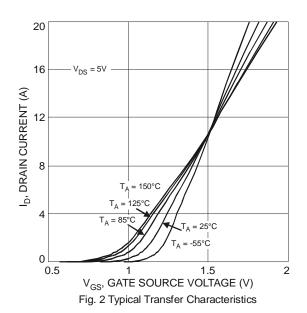
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
STATIC CHARACTERISTICS		•					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub> 20				V	$I_D = 250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_		1	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Body Leakage Current	I <sub>GSS</sub>	_		±100	nA	$V_{DS} = 0V, V_{GS} = \pm 8V$	
Gate Threshold Voltage	V <sub>GS(th)</sub>	0.5		0.9 V \		$V_{DS} = V_{GS}, I_D = 250 \mu A$	
			22	28		$V_{GS} = 4.5V, I_D = 8.2A$	
Static Drain-Source On-Resistance (Note 5)	R <sub>DS</sub> (ON)	_	25	32	mΩ	$V_{GS} = 2.5V, I_D = 3.3A$	
			31	40		$V_{GS} = 1.8V, I_D = 2.0A$	
Forward Transfer Admittance	Y <sub>FS</sub>   —		7		S	$V_{DS} = 10V, I_D = 4A$	
Diode Forward Voltage (Note 5)	$V_{SD}$	_	0.7	0.9	V	$I_S = 2.25A$ , $V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C <sub>iss</sub>	_	856	_	pF	101/1/	
Output Capacitance	Coss	_	83	_	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	$C_{rss}$	_	78		pF	1 – 1.0IVII IZ	
Gate Resisitance	$R_{G}$				Ω	$V_{GS} = 0V$ , $V_{DS} = 0V$ , $f = 1MHz$	
SWITCHING CHARACTERISTICS							
Total Gate Charge	$Q_g$	_	8.3	_	nC		
Gate-Source Charge	$Q_{gs}$	_	1.3		nC	$V_{GS} = 4.5V, V_{DS} = 10V, I_D = 8.2A$	
Gate-Drain Charge	$Q_{gd}$	_	3.1		nC		
Turn-On Delay Time	t <sub>D(on)</sub>	_	8.4		ns		
Turn-On Rise Time	t <sub>r</sub>	_	8.2		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$	
Turn-Off Delay Time	t <sub>D(off)</sub> —		40.4		ns	$R_L = 10\Omega$ , $R_G = 6\Omega$	
Turn-Off Fall Time	t <sub>f</sub> —		8.9		ns		

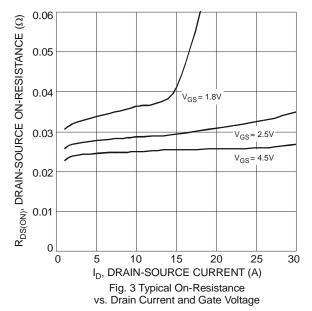
Notes:

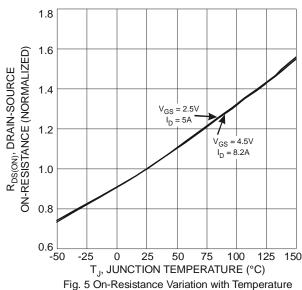
- 5. Test pulse width t = 300ms.
- 6. Guaranteed by design. Not subject to production testing.











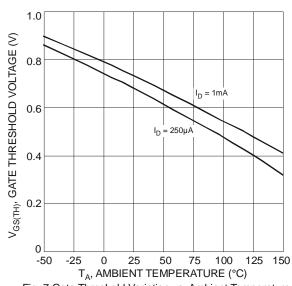


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

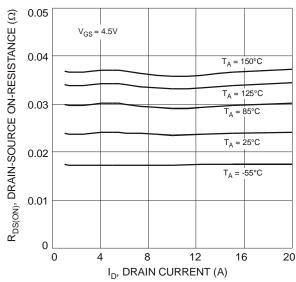


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

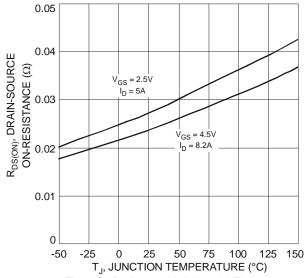


Fig. 6 On-Resistance Variation with Temperature

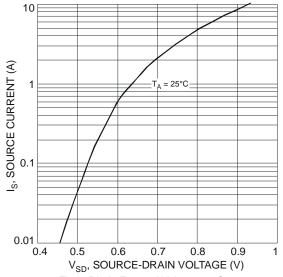
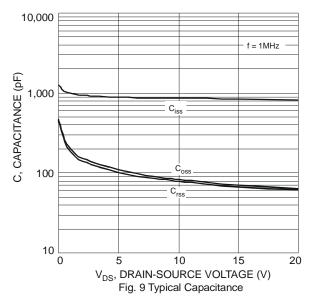


Fig. 8 Diode Forward Voltage vs. Current





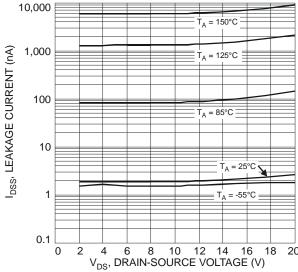


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage

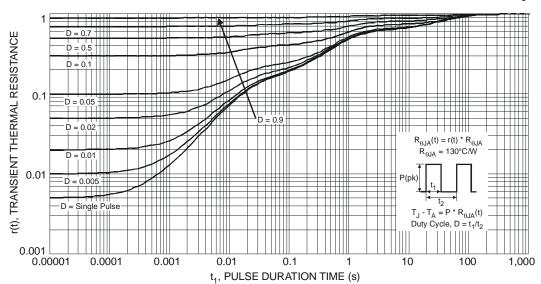


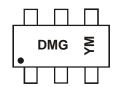
Fig. 11 Transient Thermal Response

### Ordering Information (Note 7)

Part Number	Case	Packaging
DMG9926UDM-7	SOT-26	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



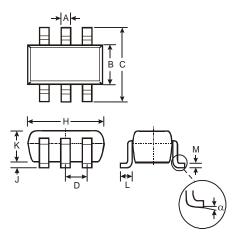
DMG = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009) M = Month (ex: 9 = September)

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	X		Υ	Z		Α	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

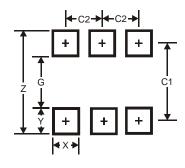


## **Package Outline Dimensions**



	SOT-26					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_	_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
М	0.10	0.20	0.15			
α	0°	8°	_			
All D	All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95



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